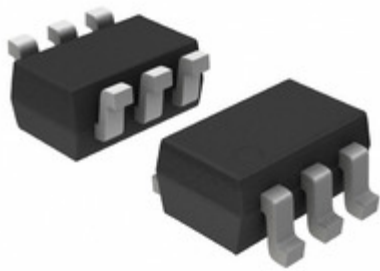
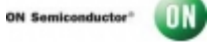

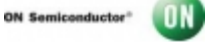


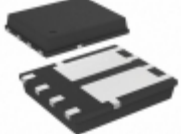

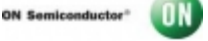
	<h2 style="color: red;">NVJD5121NT1G</h2>
	<p>Hersteller-Teilenummer: NVJD5121NT1G</p> <hr/> <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> <hr/> <p>Teil der Beschreibung: MOSFET 2N-CH 60V 0.295A SC88</p> <hr/> <p>Datenblätter:  NVJD5121NT1G.pdf</p> <hr/> <p>RoHs Status: Bleifrei / RoHS-konform</p> <hr/> <p>Lagerzustand: New original, 3000 pcs Stock Available.</p> <hr/> <p>Liefern von: Hong Kong</p> <hr/> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	NVJD5121NT1G
Hersteller	AMI Semiconductor / ON Semiconductor
Beschreibung	MOSFET 2N-CH 60V 0.295A SC88
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	3000 pcs Stock
Serie	-
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	250mW
Verpackung / Gehäuse	6-TSSOP, SC-88, SOT-363
Supplier Device-Gehäuse	SC-88/SC70-6/SOT-363
Typ FET	2 N-Channel (Dual)
FET-Merkmal	Standard
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	295mA
Rds On (Max) @ Id, Vgs	1.6 Ohm @ 500mA, 10V
VGS (th) (Max) @ Id	2.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	0.9nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	26pF @ 20V
Verpackung	Tape & Reel (TR)

NVJD5121NT1G ist neu im Original. Suche NVJD5121NT1G Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NVJD5121NT1G AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NVJD5121NT1G: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>NVJD4152PT1G AMI Semiconductor / ON Semiconductor NVJD4152PT1G ON</p>	 <p>NVJD4401NT1G AMI Semiconductor / ON Semiconductor MOSFET 2N-CH 20V 0.63A SC88</p>	 <p>NVJD4158CT1G AMI Semiconductor / ON Semiconductor NVJD4158CT1G ON</p>	 <p>NVJS4405NT1G AMI Semiconductor / ON Semiconductor MOSFET N-CH 25V 1.2A SC88</p>
 <p>NVJS4151PT1G AMI Semiconductor / ON Semiconductor MOSFET P-CH 20V 3.2A SC88</p>	 <p>SI7272DP-T1-GE3 Electro-Films (EFI) / Vishay MOSFET 2N-CH 30V 25A PPAK SO-8</p>	 <p>SSD2007ASTF AMI Semiconductor / ON Semiconductor MOSFET 2N-CH 50V 2A 8-SOIC</p>	 <p>NVJS3151PT1G AMI Semiconductor / ON Semiconductor NVJS3151PT1G ON</p>

heiße Teile

Mehr

 1812AA270JAT1A SB	 1812SA471JATME	 A3910EEETR-T	 AC0402CRNPO9BN3R0	 AK4644EN
 AP1690M-G1	 BD6775EFV	 D BSiT68H253	 C1608CH2A152J080AA	 CD74ACT08E
 CL21A225KPFNNNG	 DAC082S085C1MM/NOPB	 DEA202484HT-8002A1	 DMP2200UDW-7	 FF60UP30DN
 D GRM1885C1H6R6CA01D	 HSMP-3816-TR1G	 HT82K68A-003D	 ICS9212AF-13LFT	 ILC7082AIM5-30
 IRKD260-16	 ISL6207CB-T	 ISPLSI2032V-60LJ44	 KAI-02050-CBA-JD-BA	 LD055A3R9CAB2A
 LM22680QMRX-ADJ/NOPB	 LT1949ES8#PBF	 D MEM2012P25R0T001	 NR4010T100M	 NVJD4152PT1G
 NVJD4158CT1G	 D NVJD4401NT1G	 NVJS3151PT1G	 NVJS4151PT1G	 NVJS4405NT1G
 PIC32MX370F512L-I/PT	 PKC4131PIE	 RB751CS-40	 RQ5RW25CA-TR	 RT8086BGQUF
 S-81252SGUP	 SE15PJ-M3/84A	 SI7431DP-T1-GE3	 D SMD250F-2	 T290F08ESB
 TAR5S45U	 TB62747AFAG	 TFDU6102	 W2416NC220	 XCL206B213AR-G

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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